

Feature

- Low Collector-Emitter Saturation Voltage & Large Collector Current
- High Power Dissipation: $P_C = 1.3W$ ($T_a=25^\circ C$)
- Complementary to KSB1151



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	60	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	5	A
I_{CP}	*Collector Current (Pulse)	8	A
I_B	Base Current (DC)	1	A
P_C	Collector Dissipation ($T_a=25^\circ C$)	1.3	W
P_C	Collector Dissipation ($T_C=25^\circ C$)	20	W
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	- 55 ~ 150	$^\circ C$

* $PW \leq 10ms$, duty Cycle $\leq 50\%$

Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{CBO}	Collector Cut-off Current	$V_{CB} = 50V, I_E = 0$			10	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 7V, I_C = 0$			10	μA
h_{FE1} h_{FE2} h_{FE3}	*DC Current Gain	$V_{CE} = 1V, I_C = 0.1A$ $V_{CE} = 1V, I_C = 2A$ $V_{CE} = 1V, I_C = 5A$	60 100 50		400	
$V_{CE(sat)}$	*Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.2A$		0.1	0.3	V
$V_{BE(sat)}$	*Base-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.2A$		0.9	1.2	V
t_{ON}	Turn ON Time	$V_{CC} = 10V, I_C = 2A$ $I_{B1} = - I_{B2} = 0.2A$ $R_L = 5\Omega$		0.2	1	μs
t_{STG}	Storage Time			1.1	2.5	μs
t_F	Fall Time			0.2	1	μs

* Pulse test: $PW \leq 50\mu s$, duty Cycle $\leq 2\%$ Pulsed

h_{FE} Classification

Classification	O	Y	G
$h_{FE 2}$	100 ~ 200	160 ~ 320	200 ~ 400

Typical Characteristics

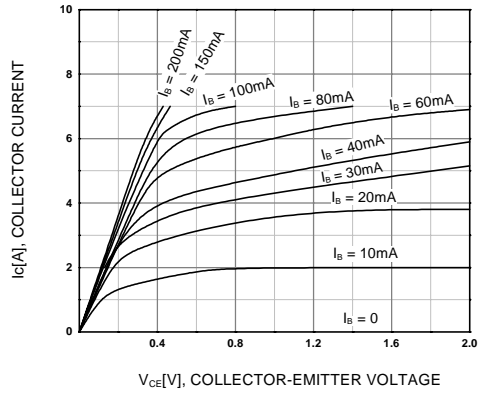


Figure 1. Static Characteristic

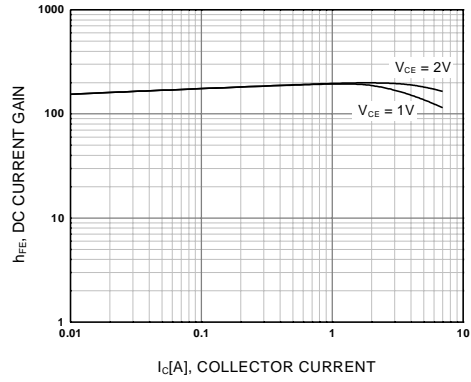


Figure 2. DC current Gain

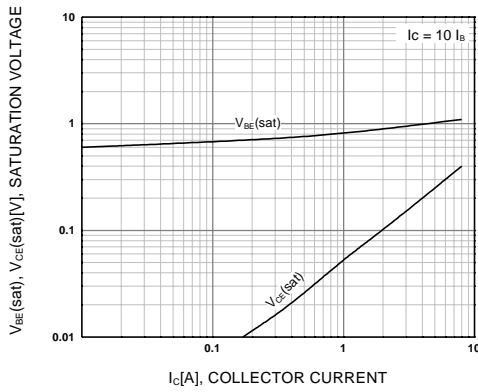


Figure 3. Collector-Emitter Saturation Voltage
Base-Emitter Saturation Voltage

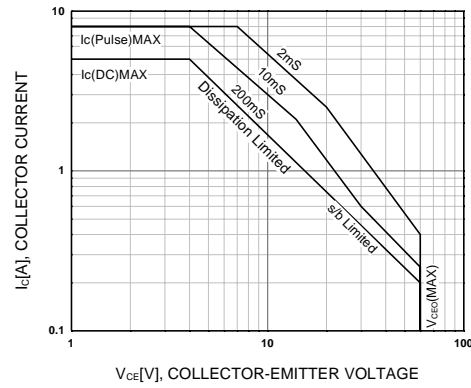


Figure 4. Forward Bias Safe Operating Area

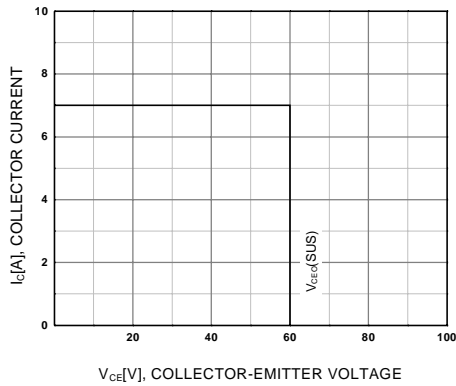


Figure 5. Reverse Bias Safe Operating Area

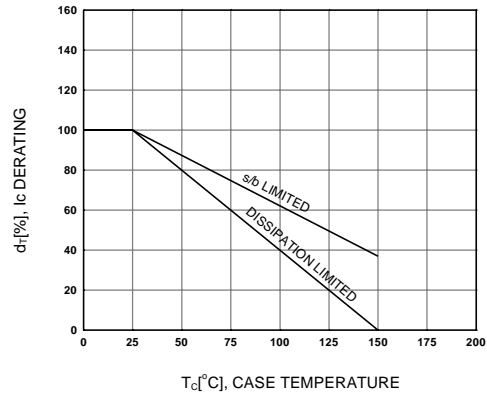


Figure 6. Derating Curve of Safe Operating Areas

Typical Characteristics (Continued)

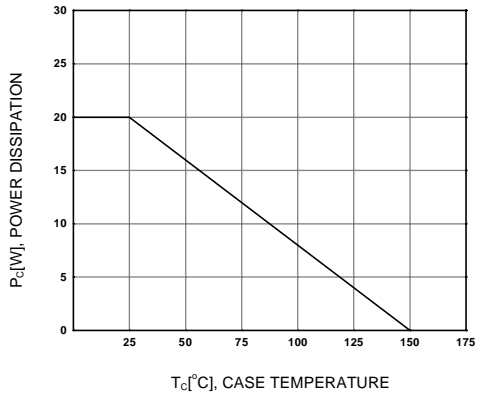


Figure 7. Power Derating

Package Dimensions

KSD1691

TO-126



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	HiSeC™	SuperSOT™-8
Bottomless™	ISOPLANAR™	SyncFET™
CoolFET™	MICROWIRE™	TinyLogic™
CROSSVOLT™	POP™	UHC™
E ² CMOS™	PowerTrench®	VCX™
FACT™	QFET™	
FACT Quiet Series™	QS™	
FAST®	Quiet Series™	
FASTr™	SuperSOT™-3	
GTO™	SuperSOT™-6	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Home >> Find products >>

KSD1691

NPN Epitaxial Silicon Transistor

Contents

- [Features](#)
- [Product status/pricing/packageing](#)
- [Order Samples](#)
- [Qualification Support](#)

Features

- Low Collector-Emitter Saturation Voltage & Large Collector Current
- High Power Dissipation: $P_C=1.3W$ ($T_a=25^\circ C$)
- Complementary to KSB1151

[back to top](#)

Product status/pricing/packageing

BUY

BUY

Datasheet

[Download this datasheet](#)



[e-mail this datasheet](#)



This page

[Print version](#)

Related Links

[Request samples](#)

[How to order products](#)

[Product Change Notices \(PCNs\)](#)



[Support](#)

[Sales support](#)

[Quality and reliability](#)

[Design center](#)

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
KSD1691GS	Full Production	Full Production	\$0.316	TO-126	3	BULK	Line 1: \$Y (Fairchild logo) &3 (3-Digit Date Code) Line 3: D1691-G
KSD1691OS	Full Production	Full Production	\$0.316	TO-126	3	BULK	Line 1: \$Y (Fairchild logo) &3 (3-Digit Date Code) Line 3: D1691-O
KSD1691YS	Full Production	Full Production	\$0.316	TO-126	3	BULK	Line 1: \$Y (Fairchild logo) &3 (3-Digit Date Code) Line 3: D1691-Y
KSD1691YSTSTU	Full Production		\$0.318	TO-126	3	RAIL	N/A

		 Full Production					
KSD1691YSTU	Full Production	 Full Production	\$0.318	TO-126	3	RAIL	Line 1: \$Y (Fairchild logo) &3 (3-Digit Date Code) Line 3: D1691-Y

* Fairchild 1,000 piece Budgetary Pricing

** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a [Fairchild distributor](#) to obtain samples



Indicates product with Pb-free second-level interconnect. For more information [click here](#).

Package marking information for product KSD1691 is available. [Click here for more information](#).

[back to top](#)

Qualification Support

Click on a product for detailed qualification data

Product
KSD1691GS
KSD1691OS
KSD1691YS
KSD1691YSTSTU
KSD1691YSTU

[back to top](#)

© 2007 Fairchild Semiconductor

